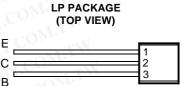
- 20 W Pulsed Power Dissipation
- 100 V Capability
- 2 A Continuous Collector Current
- 4 A Peak Collector Current
- Customer-Specified Selections Available



MDTRAB

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	W .	SYMBOL	VALUE	UNIT
Collector-base voltage (I _E = 0)	TIPP31 TIPP31A TIPP31B TIPP31C	V _{CBO}	40 60 80 100	V
Collector-emitter voltage (I _B = 0)	V _{CEO}	40 60 80 100	V	
Emitter-base voltage			5	V
Continuous collector current			2	Α
Peak collector current (see Note 1)			4	A
Continuous base current			10 ^M	Α
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			0.8	W
Pulsed power dissipation (see Note 3)			20	W
Operating junction temperature range			-55 to +150	°C
Storage temperature range	DAY TAN	T _{stg}	-55 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			260	°C

NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$.

2. Derate linearly to 150°C case temperature at the rate of 6.4 mW/°C.

3. V_{CE} = 20 V, I_{C} = 1 A, t_{p} = 10 ms, duty cycle \leq 2%.

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TIPP31, TIPP31A, TIPP31B, TIPP31C NPN SILICON POWER TRANSISTORS

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electrical characteristics at 25°C case temperature

	PARAMETER	COM	TEST CONDITION	ONS	■ MIN	TYP	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	$I_C = 5 \text{ mA}$ (see Note 4)	I _B = 0	TIPP31 TIPP31A TIPP31B TIPP31C	40 60 80 100			V
I _{CES}	Collector-emitter cut-off current	$V_{CE} = 40 \text{ V}$ $V_{CE} = 60 \text{ V}$ $V_{CE} = 80 \text{ V}$ $V_{CE} = 100 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	TIPP31 TIPP31A TIPP31B TIPP31C	I.TV		0.2 0.2 0.2 0.2	mA
I _{CEO}	Collector cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$	TIPP31/31A TIPP31B/31C	OM.	W	0.3 0.3	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	I _C = 0	MMM.100X	CO_{M}	WT	1	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_C = 1 A$ $I_C = 2 A$	(see Notes 4 and 5)	20 10	M.TV		
V _{CE(sat)}	Collector-emitter saturation voltage	I _B = 375 mA	I _C = 2 A	(see Notes 4 and 5)	N.C.	om.T	1	V
V _{BE}	Base-emitter voltage	V _{CE} = 4 V	I _C = 2 A	(see Notes 4 and 5)	007.	OM.	1.5	V
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 0.5 A	f = 1 kHz	20	COE	WT.1	:T
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 0.5 A	f = 1 MHz	3	V.CC	T.M	N N

NOTES: 4. These parameters must be measured using pulse techniques, $t_p = 300 \mu s$, duty cycle $\leq 2\%$.

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^{5.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts. WWW.100Y.CO WWW.100Y.C WWW.100Y.C WWW.100Y.COM.TW

TIPP31, TIPP31A, TIPP31B, TIPP31C NPN SILICON POWER TRANSISTORS

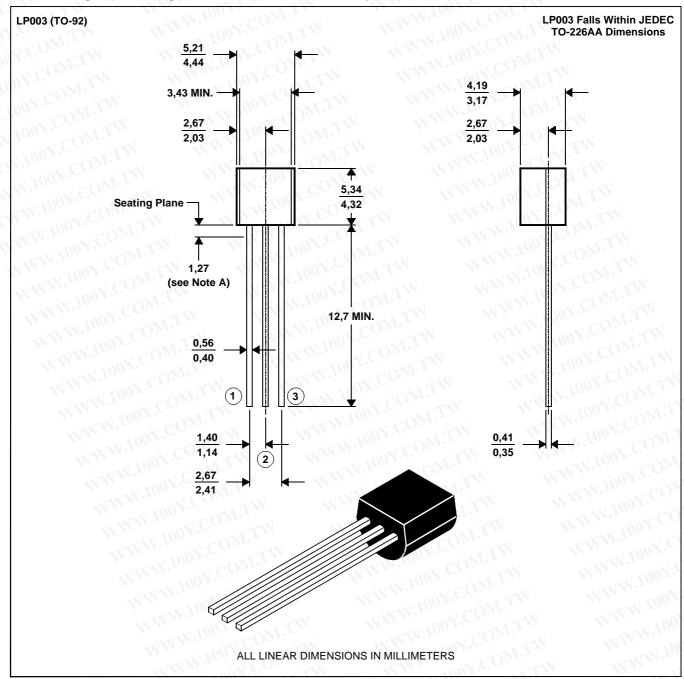
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MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: Lead dimensions are not controlled in this area.

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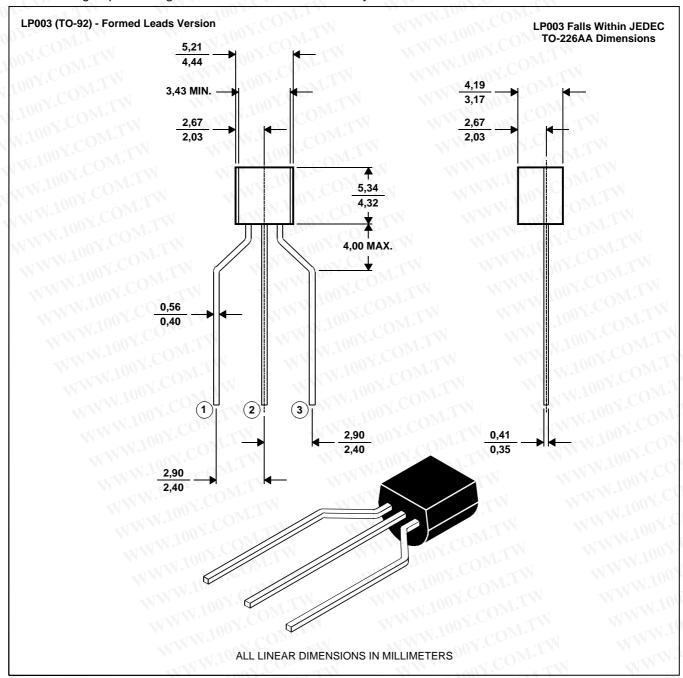
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MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.

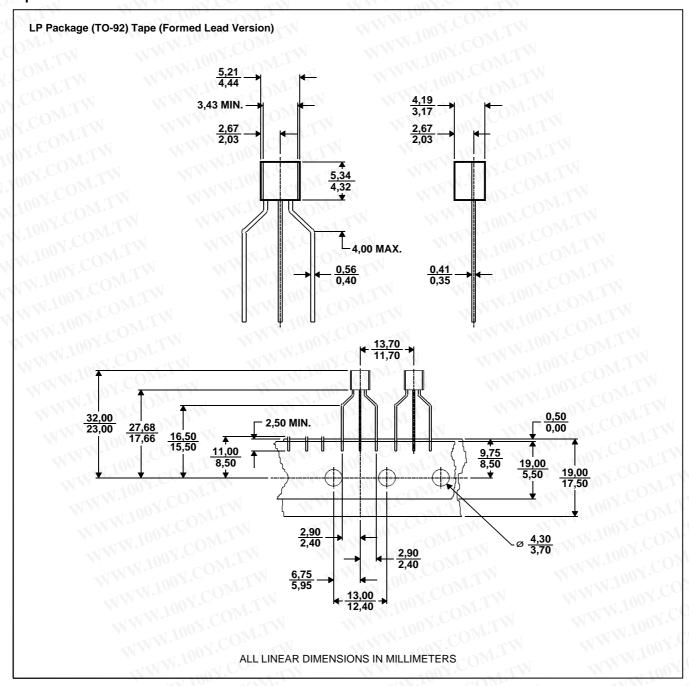


MDXXAR

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MECHANICAL DATA

LPR tape dimensions



MDXXAS

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